

FEATURES

Class AB linear GaN design
 Instantaneous ultra-broad Bandwidth
 Suitable for all single channel modulation standards
 Built-in protection circuits
 High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	10 - 6000 MHz	
Power Output Psat	2 Watt Min	CW
Power Output P1dB GCP	1 Watt Typ	CW
Small Signal Gain	33 dB Min	
Power Gain Flatness	6 dB p-p Max	
Input Return Loss	-10 dB Typ	
2-Tone Intermodulation (IMD)	-30 dBc Typ	23dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	-20 dBc Typ	At rated Pout
Noise Figure	10 dB Max	
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	28 VDC $\pm 0.2\text{ V}$	
Current Consumption	1.0 Amp Max	At rated Pout
Input Power Protection	+8 dBm Max	< 10 Sec without damage
Load VSWR Protection	5 : 1 Max	<1 minute @ rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +70 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	90 x 85 x 22 mm	Excluding connectors
Weight	350 gr.	
RF Connectors In/Out	SMA female	
DC Power	Feed Thru	
Cooling	External Heatsink	Forced air required

PIN ASSIGNMENT

Pin	Function	Description
1	DC Voltage	+28VDC
2	GND	GND

OUTLINE DRAWING

